## **Freescale Semiconductor**

**Technical Data** 

# **CATV Amplifier Module**

### **Features**

- Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- · Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

### **Applications**

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation

# Description

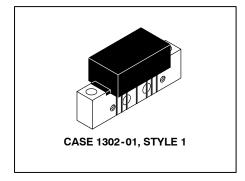
- www.DateSt24Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module
  - Replaced MHW8182C. There are no form, fit or function changes with this
    part replacement.
  - RoHS Compliant

Document Number: MHW8182CN Rev. 3, 4/2006

**VROHS** 

# **MHW8182CN**

860 MHz 19.1 dB GAIN 128-CHANNEL CATV AMPLIFIER MODULE



**Table 1. Maximum Ratings** 

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+70	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

**Table 2. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted)

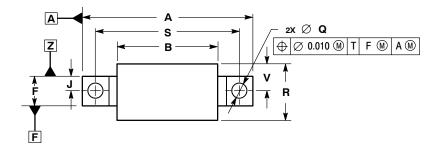
Characteristic Frequency Range		Symbol	<b>Min</b> 40	Тур	<b>Max</b> 860	Unit MHz
		BW				
Power Gain	50 MHz 860 MHz	G <sub>p</sub>	18 18.2	18.5 19.1	19 20.5	dB
Slope	40 - 860 MHz	S	0	0.7	2.5	dB
Gain Flatness (40 - 860 MHz, Peak to Valley)		G <sub>F</sub>	_	0.3	0.6	dB
Return Loss — Input/Output (Z <sub>0</sub> = 75 Ohms)		IRL/ORL				
	@ 40 MHz @ f > 40 MHz (Derate)		20 —	_ _	 0.005	dB dB/MHz
Composite Second Order	100 Channel ELAT	000		74	0.4	dBc
(V <sub>out</sub> = +38 dBmV/ch., Worst Case) (V <sub>out</sub> = +40 dBmV/ch., Worst Case) (V <sub>out</sub> = +44 dBmV/ch., Worst Case)	128-Channel FLAT 110-Channel FLAT 77-Channel FLAT	CSO <sub>128</sub> CSO <sub>110</sub> CSO <sub>77</sub>	_ _ _	-71 -70 -70	-64 -63 -64	

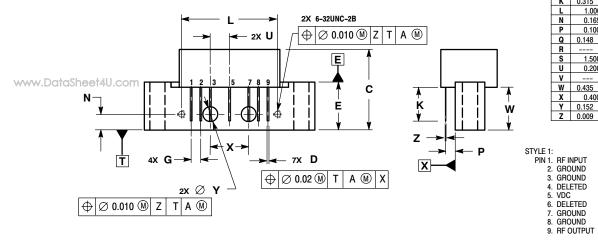
**Table 2. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted) (continued)

Characteristic		Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion @ Ch 2						dBc
(V <sub>out</sub> = +38 dBmV/ch., FM = 55 MHz)	128-Channel FLAT	XMD <sub>128</sub>	_	-68	-65	
$(V_{out} = +40 \text{ dBmV/ch.}, FM = 55 \text{ MHz})$	110-Channel FLAT	XMD <sub>110</sub>		-66	-64	
$(V_{out} = +44 \text{ dBmV/ch.}, FM = 55 \text{ MHz})$	77-Channel FLAT	XMD <sub>77</sub>	_	-61	-59	
Composite Triple Beat						dBc
(Vout = +38 dBmV/ch., Worst Case)	128-Channel FLAT	CTB <sub>128</sub>	_	-69	-66	
(V <sub>out</sub> = +40 dBmV/ch., Worst Case)	110-Channel FLAT	CTB <sub>110</sub>		-68	-66	
$(V_{out} = +44 \text{ dBmV/ch.}, \text{Worst Case})$	77-Channel FLAT	CTB <sub>77</sub>	_	-66	-64	
Noise Figure	50 MHz	NF	_	4.0	5.0	dB
-	550 MHz			4.5	_	
	750 MHz			5.0	6.5	
	860 MHz		_	5.5	7.5	
DC Current ( $V_{DC} = 24 \text{ V}, T_C = 30^{\circ}\text{C}$ )		I <sub>DC</sub>	180	220	240	mA

www.DataSheet4U.com

# **PACKAGE DIMENSIONS**





- NOTES:
  1. CONTROLLING DIMENSION: INCH.
  2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Е	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.620	8.255	
G	0.100 BSC		2.540 BSC		
7	0.156	BSC	3.962	BSC	
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
Р	0.100 BSC		2.540 BSC		
œ	0.148	0.168	3.759	4.267	
R		0.600		15.240	
S	1.500 BSC		38.100 BSC		
U	0.200 BSC		5.080 BSC		
٧		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC		10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

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